NSN 5961-00-817-6403

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Inclosure Material:

Metal

Overall Length:

0.650 inches

Overall Diameter:

0.850 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Gate

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.250 inches

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 28.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 500.00 milliamperes source cutoff current and 12.00 amperes source cutoff current

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Thread Series Designator:

Unf

Terminal Type And Quantity:

4 tab, solder lug

Specification Data:

80131-release2571 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0